

**Vishay Semiconductors** 

9612009

## **Small Signal Switching Diodes, High Voltage**

#### Features

- Silicon epitaxial planar diodes
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

## Applications

General purposes

### **Mechanical Data**

Case: QuadroMELF SOD-80 Weight: approx. 34 mg Cathode band color: black Packaging codes/options: GS18/10 k per 13" reel (8 mm tape), 10 k/box

GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

#### Parts Table

| Part   | Type differentiation     | Ordering code              | Type marking | Remarks       |
|--------|--------------------------|----------------------------|--------------|---------------|
| BAV200 | V <sub>RRM</sub> = 60 V  | BAV200-GS18 or BAV200-GS08 | -            | Tape and reel |
| BAV201 | V <sub>RRM</sub> = 120 V | BAV201-GS18 or BAV201-GS08 | -            | Tape and reel |
| BAV202 | V <sub>RRM</sub> = 200 V | BAV202-GS18 or BAV202-GS08 | -            | Tape and reel |
| BAV203 | V <sub>RRM</sub> = 250 V | BAV203-GS18 or BAV203-GS08 | -            | Tape and reel |

**RoHS** COMPLIANT

## **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter                  | Test condition                               | Part   | Symbol           | Value | Unit |
|----------------------------|--|--------|------------------|-------|------|
|                            |  | BAV200 | V <sub>RRM</sub> | 60    | V    |
| Deals reverse veltage      |  | BAV201 | V <sub>RRM</sub> | 120   | V    |
| Peak reverse voltage       |  | BAV202 | V <sub>RRM</sub> | 200   | V    |
|                            |  | BAV203 | V <sub>RRM</sub> | 250   | V    |
|                            |  | BAV200 | V <sub>R</sub>   | 50    | V    |
| Boyoroo voltogo            |  | BAV201 | V <sub>R</sub>   | 100   | V    |
| Reverse voltage            |  | BAV202 | V <sub>R</sub>   | 150   | V    |
|                            |  | BAV203 | V <sub>R</sub>   | 200   | V    |
| Forward continuous current |  |        | ١ <sub>F</sub>   | 250   | mA   |
| Peak forward surge current | t <sub>p</sub> = 1 s, T <sub>j</sub> = 25 °C |        | I <sub>FSM</sub> | 1     | А    |
| Forward peak current       | f = 50 Hz                                    |        | I <sub>FM</sub>  | 625   | mA   |
| Power dissipation          |  |        | P <sub>tot</sub> | 500   | mW   |



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## **Thermal Characteristics**

#### T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter                                  | Test condition                        | Symbol            | Value         | Unit |  |
|--|---------------------------------------|-------------------|---------------|------|--|
| Thermal resistance junction to ambient air | On PC board<br>50 mm x 50 mm x 1.6 mm | R <sub>thJA</sub> | 500           | K/W  |  |
| Junction temperature                       |                                       | Tj                | 175           | °C   |  |
| Storage temperature range                  |                                       | T <sub>stg</sub>  | - 65 to + 175 | °C   |  |

## **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter                       | Test condition  | Part   | Symbol            | Min. | Тур. | Max. | Unit |
|---------------------------------|---|--------|-------------------|------|------|------|------|
| Forward voltage                 | I <sub>F</sub> = 100 mA   |        | V <sub>F</sub>    |      |      | 1000 | mV   |
| Reverse current                 | V <sub>R</sub> = 50 V   | BAV200 | I <sub>R</sub>    |      |      | 100  | nA   |
|                                 | V <sub>R</sub> = 100 V  | BAV201 | I <sub>R</sub>    |      |      | 100  | nA   |
|                                 | V <sub>R</sub> = 150 V  | BAV202 | I <sub>R</sub>    |      |      | 100  | nA   |
|                                 | V <sub>R</sub> = 200 V  | BAV203 | I <sub>R</sub>    |      |      | 100  | nA   |
|                                 | $T_j = 100 \ ^{\circ}C, \ V_R = 50 \ V$                                     | BAV200 | I <sub>R</sub>    |      |      | 15   | μA   |
|                                 | T <sub>j</sub> = 100 °C, V <sub>R</sub> = 100 V                             | BAV201 | I <sub>R</sub>    |      |      | 15   | μA   |
|                                 | T <sub>j</sub> = 100 °C, V <sub>R</sub> = 150 V                             | BAV202 | I <sub>R</sub>    |      |      | 15   | μA   |
|                                 | T <sub>j</sub> = 100 °C, V <sub>R</sub> = 200 V                             | BAV203 | I <sub>R</sub>    |      |      | 15   | μA   |
| Breakdown voltage               | $I_R = 100 \ \mu A, t_p/T = 0.01,$<br>$t_p = 0.3 \ ms$                      | BAV200 | V <sub>(BR)</sub> | 60   |      |      | V    |
|                                 |   | BAV201 | V <sub>(BR)</sub> | 120  |      |      | V    |
|                                 |   | BAV202 | V <sub>(BR)</sub> | 200  |      |      | V    |
|                                 |   | BAV203 | V <sub>(BR)</sub> | 250  |      |      | V    |
| Diode capacitance               | V <sub>R</sub> = 0, f = 1 MHz   |        | CD                |      | 1.5  |      | pF   |
| Differential forward resistance | I <sub>F</sub> = 10 mA  |        | r <sub>f</sub>    |      | 5    |      | Ω    |
| Reverse recovery time           | $I_{F} = I_{R} = 30 \text{ mA}, i_{R} = 3 \text{ mA},$ $R_{L} = 100 \Omega$ |        | t <sub>rr</sub>   |      |      | 50   | ns   |

## **Typical Characteristics**

 $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

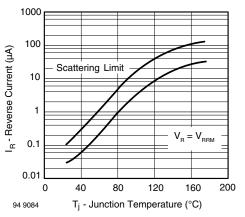


Figure 1. Reverse Current vs. Junction Temperature

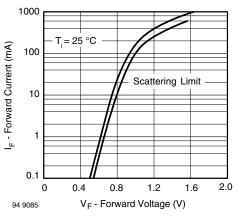


Figure 2. Forward Current vs. Forward Voltage



# BAV200, BAV201, BAV202, BAV203

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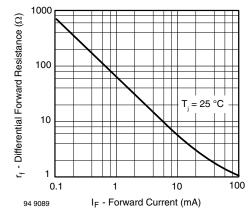
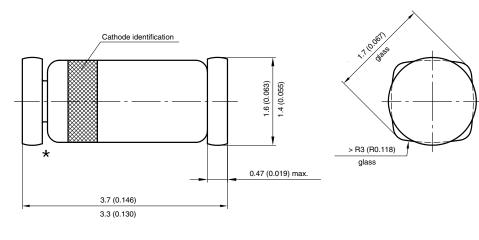
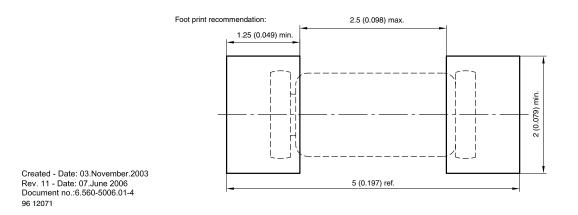


Figure 3. Differential Forward Resistance vs. Forward Current

### Package Dimensions in millimeters (inches): QuadroMELF SOD-80



<sup>★</sup> The gap between plug and glass can be either on cathode or anode side



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